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PES University, Bangalore (Established under Karnataka Act No. 16 of 2013)

UE20EC101

DEC 2021: END SEMESTER ASSESSMENT- B.TECH. I/II SEMESTER UE20EC101 -Electronic Principles and Devices

Tin	ne: 1	80 mins Answer All Questions Max Marks: 100	00
1.	a	Give the Difference between the following.	SM
		(i) Avalanche Breakdown and Zener Breakdown	
		(ii) Static Resistance and Dynamic Resistance	
		(iii) Ideal diode and Practical diode	
	Ъ	Solve the following using second approximation for a diode.	ВМ
		(i) Determine Vo and I _D	
,		+8 V 1.2 kΩ V _o	
		$I_D \downarrow \sum_{n=6}^{4.7} k\Omega$	
		(ii) Determine I ₁ , I ₂ and V ₁ for the circuit shown in the Figure below	
		$E = \begin{bmatrix} I_1 & Si \\ D_1 & I_2 \\ \hline 18V & D_2 \end{bmatrix} $ Si $= \begin{bmatrix} I_1 & Si \\ 2.2K\Omega \\ \hline -V_1 + \\ \hline 4.7K\Omega \end{bmatrix}$	
	С	Using Shockley's equation, Find the diode current I_d for a silicon Diode, if the applied voltage V_D =0.71 and Reverse Saturation Current is 4 x 10 ⁻¹² A at a temp of 30 ⁰ C. Consider (η =1).	6M
2.	a	With a neat circuit diagram and waveforms explain Half wave Rectifier 6	6M
	b	Derive the expression for I _{dc} , I _{rms} and hence find the Efficiency for Full wave Rectifier 8	ВМ
	С	Determine the range of values of Vi that will maintain the Zener diode in the "on" 6 state.	6 M

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		$V_{L} = \frac{I_{R}}{V_{L}}$ $V_{L} = \frac{18V}{I_{ZM}} = 60 \text{ mA}$ $V_{L} = \frac{1}{1} \text{ mA}$ $V_{L} = \frac{1}{1} \text{ mA}$				
3.	a	Find the Min-terms for the function $F = AB+BC+AC$ by Converting into canonical SOP. Realize the SOP using Basic Gates.	6 M			
	b	Using Truth Table for Full Adder Realize Full Adder using (i) XOR gates (ii) Basic Gates.	8 M			
	С	Discuss the following Sequential Circuits using Circuit diagram and Characteristic Table (i) JK Flip Flop (ii) 3 bit Asynchronous up-counter	6 M			
4.	a	With a neat diagram explain the Input and output V-I characteristics of NPN BJT Common Emitter Characteristics.	6M			
	b	Derive the relation between α and β and Find the value of I_B , α and β if $I_E = 1.2 \text{mA}$ and $I_C = 1.15 \text{mA}$.				
	С	Explain Cellular Communication with a neat diagram.				
5	a	What are the Characteristics of Embedded System and discuss the types of embedded systems based on Generation.				
	Ъ	Draw the Data Flow Model of ARM Processor and explain the same.				
	С	Mention the Differences between Microprocessor and Microcontroller.				